

isc N-Channel MOSFET Transistor

FCPF190N60

FEATURES

- · With TO-220F packaging
- · High speed switching
- · Low gate input resistance
- · Standard level gate drive
- · Easy to use
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



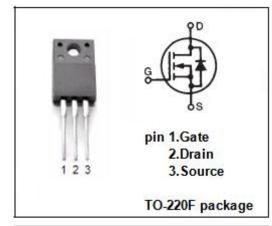
- Power supply
- · Switching applications

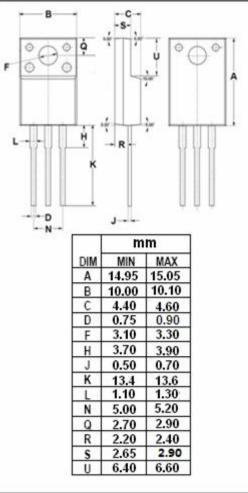
• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

| SYMBOL | PARAMETER | VALUE | UNIT |
|------------------|-----------------------------------|-------|------------|
| V _{DSS} | Drain-Source Voltage | 600 | V |
| V _{GSS} | Gate-Source Voltage | ±20 | V |
| I _D | Drain Current-Continuous;@Tc=25℃ | 20.2 | А |
| I _{DM} | Drain Current-Single Pulsed | 60.6 | А |
| P _D | Total Dissipation | 39 | W |
| T _j | Operating Junction Temperature -5 | | $^{\circ}$ |
| T _{stg} | Storage Temperature -55~150 | | $^{\circ}$ |

• THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | MAX | UNIT |
|-----------|------------------------------------|-----|------|
| Rth(ch-c) | Channel-to-case thermal resistance | 3.2 | °C/W |





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ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | MIN | ТҮР | MAX | UNIT |
|---------------------|--------------------------------|--|-----|-----|------|------|
| BV _{DSS} | Drain-Source Breakdown Voltage | V _{GS} =0V; I _D = 10mA | 600 | | | V |
| V _{GS(th)} | Gate Threshold Voltage | V _{DS} =V _{GS} ; I _D =250uA | 2.5 | | 3.5 | V |
| R _{DS(on)} | Drain-Source On-Resistance | V _{GS} = 10V; I _D = 10A | | | 199 | mΩ |
| I _{GSS} | Gate-Source Leakage Current | V _{GS} =±20V;V _{DS} = 0V | | | ±100 | nA |
| I _{DSS} | Drain-Source Leakage Current | V _{DS} = 480V; V _{GS} = 0V | | | 1 | μА |
| V _{SDF} | Diode forward voltage | I _{SD} =10A, V _{GS} = 0 V | | | 1.2 | V |

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